## NSN 5961-01-044-2666

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**Inclosure Material:** 

Metal all transistor

**Overall Length:** 

0.120 inches all transistor and 0.140 inches all transistor

**Terminal Length:** 

0.500 inches all transistor

**Overall Diameter:** 

0.192 inches all transistor and 0.222 inches all transistor

**Internal Configuration:** 

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-106 all transistor

**Internal Junction Configuration:** 

Pnp all transistor

**Component Function Relationship:** 

Matched

**Component Name And Quantity:** 

2 transistor

**Mounting Method:** 

Terminal all transistor

**Terminal Circle Diameter:** 

0.095 inches all transistor and 0.105 inches all transistor

**Features Provided:** 

Hermetically sealed case

**Semiconductor Material:** 

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

12.0 breakdown voltage, collector-to-emitter, base open all transistor

**Current Rating Per Characteristic:** 

80.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector absolute all transistor

**Maximum Operating Tempurature Per Measurement Point:** 

125.0 degrees celsius junction all transistor

**Terminal Type And Quantity:** 

4 uninsulated wire lead all transistor

Shelf Life:

N/a

**Unit Of Measure:** 

Demilitarization:

No

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